Report No. RXA1204-0050HAC01

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# ANSI C63.19 TEST REPORT

Product Name	HSUPA/HSDPA/UMTS dual band / GSM quad bands mobile phone
Model Name	GIN S
Marketing Name	one touch 918 S
FCC ID	RAD260
Client	TCT Mobile Limited

TA Technology (Shanghai) Co., Ltd.

### **GENERAL SUMMARY**

Product Name	HSUPA/HSDPA/UMTS dual band / GSM quad bands mobile phone	Model	GIN S
Report No.	RXA1204-0050HAC01	FCC ID	RAD260
Client	TCT Mobile Limited		
Manufacturer	TCT Mobile Limited		
Reference Standard(s)	ANSI C63.19-2007: American Natio Compatibility between Wireless Cor		
Conclusion	This portable wireless equipment has the relevant standards.  General Judgment: M3 (RF Emission (St.))		地上土田音
Comment	The test result only responds to the	measured sample	

Approved by Director Revised by SAR Manager SAR Engineer

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#### 1. General Information

#### 1.1. Notes of the Test Report

**TA Technology (Shanghai) Co., Ltd.** guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

**TA Technology (Shanghai) Co., Ltd.** is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

This report standalone dose not constitute or imply by its own an approval of the product by the certification Bodies or competent Authorities. This report cannot be used partially or in full for publicity and/or promotional purposes without previous written approval of **TA Technology (Shanghai) Co., Ltd.** and the Accreditation Bodies, if it applies.

If the electrical report is inconsistent with the printed one, it should be subject to the latter.

#### 1.2. Testing Laboratory

Company: TA Technology (Shanghai) Co., Ltd.

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City: Shanghai Post code: 201201

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#### 1.3. Applicant Information

Company: TCT Mobile Limited

5F, E building, No. 232, Liang Jing Road ZhangJiang High-Tech Park, Pudong Area Address:

Shanghai, P.R. China. 201203

City: Shanghai

Postal Code: 201203

Country: P.R. China

Contact: Gong Zhizhou

Telephone: 0086-21-61460890

Fax: 0086-21-61460602

#### 1.4. Manufacturer Information

Company: TCT Mobile Limited

Address: 5F, E building, No. 232, Liang Jing Road ZhangJiang High-Tech Park, Pudong Area

Shanghai, P.R. China. 201203

City: Shanghai

Postal Code: 201203

Country: P.R. China

Telephone: 0086-21-61460890

Fax: 0086-21-61460602

### 1.5. Information of EUT

#### **General Information**

Device Type:	Portable Device			
Product Name:	HSUPA/HSDPA/UMTS dual band / GSM quad bands mobile phone			
IMEI:	013122000000742			
Hardware Version:	PIO			
Software Version:	SW31H_AWS			
Antenna Type:	Internal Antenna			
Device Operating Configurations:				
	GSM 850/ GSM 1900;	(tested)		
	WCDMA Band IV; (tes	ted)		
Supporting Mode(s):	GSM 900/GSM 1800;	(untested)		
	WCDMA Band I; (unte	sted)		
	Bluetooth/WiFi; (untes	ted)		
Test Modulation:	(GSM)GMSK; (WCDM	A) QPSK		
Device Class:	В			
HSDPA UE Category:	8			
HSUPA UE Category:	6			
	Max Number of Timeslots in Uplink		4	
GPRS Multislot Class(12):	Max Number of Timeslots in Downlink		4	
	Max Total Timeslot		5	
	Max Number of Timeslots in Uplink		4	
EGPRS Multislot Class(12):	Max Number of Timeslots in Downlink		4	
	Max Total Timeslot		5	
	Mode	Tx (MHz)	Rx (MHz)	
Operating Frequency Range(s):	GSM 850	824.2 ~ 848.8	869.2 ~ 893.8	
perating requeits range(s).	GSM 1900	1850.2 ~ 1909.8	1930.2 ~ 1989.8	
	WCDMA Band IV	1712.4 ~ 1752.6	2112.4 ~ 2152.6	
Test Channel:	128-190-251 (0	SSM 850) (tested)		
(Low - Middle - High)	512-661-810 (GSM 1900) (tested)			
(2011	1312 - 1413 - 1513	(WCDMA Band IV)	(tested)	
	GSM 850: 4, tested wi	•		
Power Class:	GSM 1900: 1, tested w	•		
WCDMA Band IV: 3, tested with power control all up bits				

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#### **Auxiliary Equipment Details**

Name	Model	Manufacturer	S/N
Battery 1	CAB31P0000C2	BAK	BAK2011060100278
Battery 2	CAB31P0000C1	BYD	B109151ABBA

Equipment Under Test (EUT) is a HSUPA/HSDPA/UMTS dual band / GSM quad bands mobile phone. The detail about EUT and Lithium Battery is in chapter 1.5 in this report. The device has an internal antenna for GSM/WCDMA Tx/Rx, and the other is BT/WiFi antenna that is used for Tx/Rx. It has Personal Wireless Routers (hot spots) function and Proximity Sensor function. HAC is tested for GSM 850, GSM 1900 and WCDMA Band IV. BT/WiFi mode doesn't have voice capability, and does not operate in the held to ear mode for providing handset service.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

#### 1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C		
Relative humidity	Min. = 0%, Max. = 80%		
Ground system resistance	< 0.5 Ω		
Ambient noise is checked and found very low and in compliance with requirement of standards.			
Reflection of surrounding objects is minimize	ed and in compliance with requirement of standards.		

#### 1.7. The Total M-rating of each tested band

Mode	Rating
GSM 850	М3
GSM 1900	М3
WCDMA Band IV	M4

#### 1.8. Test Date

The test performed from April 20, 2012 to April 21, 2012.

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#### 2. Test Information

#### 2.1. Operational Conditions during Test

#### 2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. The EUT holder is on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

#### 2.1.2. GSM/WCDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radiofrequency Channel Number (ARFCN) is allocated to 128, 190 and 251 in the case of GSM 850, to 512, 661 and 810 in the case of GSM 1900, to 1312, 1413 and 1513 in the case of WCDMA Band IV. The EUT is commanded to operate at maximum transmitting power. Using E5515C the power lever is set to "5" for GSM 850, set to "0" for GSM 1900. Set to all up bits for WCDMA. The test in the bands of GSM 850/GSM 1900 and WCDMA Band IV are performed in the mode of speech transfer function.

#### 2.2. HAC RF Measurements System Configuration

#### 2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY4 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

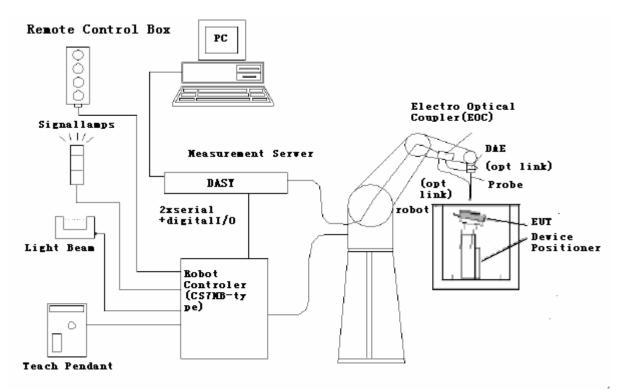


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

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#### 2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

#### **E-Field Probe Description**

Construction One dipole parallel, two dipoles normal to probe

axis Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy

±6.0%, k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity  $\pm 0.2 \text{ dB}$  in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements
Fast automatic scanning in phantoms

#### **H-Field Probe Description**

Construction Three concentric loop sensors with 3.8 mm loop

diameters

Resistively loaded detector diodes for linear

response

Built-in shielding against static charges

PEEK enclosure material (resistant to organic

solvents, e.g., glycolether)

Frequency 200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2);

Output linearized

Directivity  $\pm 0.2 \text{ dB (spherical isotropy error)}$ 

Dynamic Range 10 mA/m to 2 A/m at 1 GHz

E-Field < 10% at 3 GHz (for plane wave)

Interference

Dimensions Overall length: 330 mm (Tip: 40 mm)

Tip diameter: 6 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 3 mm



Figure 2 ER3DV6 E-field
Probe



Figure 3 H3DV6 H-field
Probe

Application General magnetic near-field measurements up to 3

GHz (in air or liquids)

Field component measurements Surface current measurements

Low interaction with the measured field

#### 2.2.3. Test Arch Phantom & Phone Positioner

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The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions:  $370 \times 370 \times$ 

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the "user point \Height Check 0.5 mm" is 0.5mm above the center, allowing verication of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field <±0.5 dB.

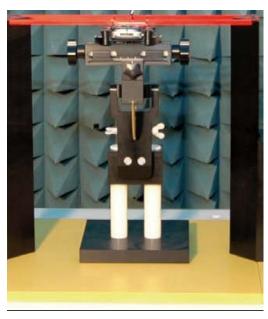


Figure 4 HAC Phantom & Device Holder

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#### 2.3. RF Test Procedures

#### The evaluation was performed with the following procedure:

- 1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
- 3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5. Record the reading.
- 6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
- 8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
- 9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
- 10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
- 11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.



Figure 5 WD reference and plane for RF emission measurements

#### 2.4. System Check

#### **Validation Procedure**

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.

The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.

The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements. Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target refenence values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

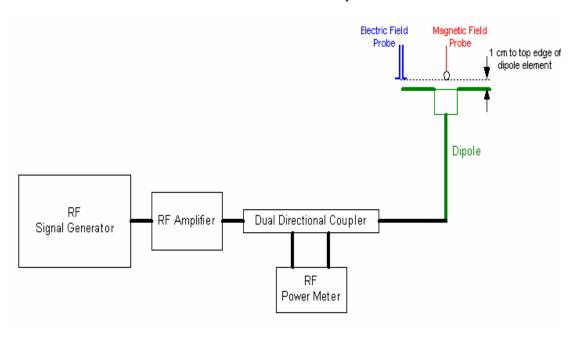


Figure 6 Dipole Validation Setup

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#### **Dipole Measurement Summary**

	E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Value	Value			
			Target <sup>1</sup> Value(V/m)	161.4	February 21, 2012		
CW	835	100	Measured <sup>2</sup> Value(V/m)	159.1	April 21, 2012		
			Deviation <sup>3</sup> (%)	1.43	1		
			Target <sup>1</sup> Value(V/m)	143.4	February 21, 2012		
CW	1880	100	Measured <sup>2</sup> Value(V/m)	125.0	April 21, 2012		
			Deviation <sup>3</sup> (%) 12.83		/		
			H-Field Scan				
Mode	Frequency (MHz)	Input Power (mW)	r Value Test Date				
			Target <sup>1</sup> Value(A/m)	0.46	February 21, 2012		
CW	835	100	Measured <sup>2</sup> Value(A/m)	0.485	April 20, 2012		
			Deviation <sup>3</sup> (%)	-5.43	1		
			Target <sup>1</sup> Value(A/m)	0.47	February 21, 2012		
CW	1880	100	Measured <sup>2</sup> Value(A/m)	0.456	April 20, 2012		

Notes: 1. Target value is provided by SPEAD in the calibration certificate of specific dipoles.

- 2. Please refer to the attachment for detailed measurement data and plot.
- 3. Deviation (%) = 100 \* (Target value minus Measured value) divided by Target value.

#### 2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

#### **Modulation Factor Test Procedure**

This may be done using the following procedure:

- 1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
- 2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
- 3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
- 4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
- 5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
- 6. Record the reading of the probe measurement system of the unmodulated signal.
- 7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor.  $PMF_E = E_{CW} / E_{mod} (PMF_H = H_{CW} / H_{mod})$
- 8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

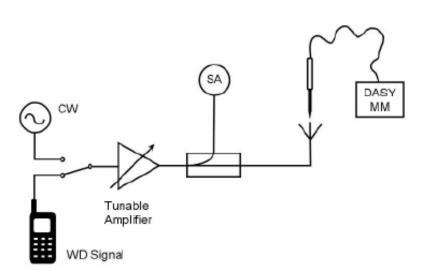


Figure 7 Probe Modulation Factor Test Setup

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#### PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
GSM 850	2.81	2.75
GSM 1900	2.84	2.84
WCDMA Band IV	1.02	1.01

#### 2.6. Conducted Output Power Measurement

#### **Summary**

The EUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

#### **Conducted Power Results**

GSM 850	Conducted Power(dBm)			
G3W 630	Channel 128	Channel 190	Channel 251	
Test Results	32.85	32.84	32.84	
GSM 1900	Conducted Power(dBm)			
G3W 1900	Channel 512	Channel 661	Channel 810	
Test Results	29.22	29.43	29.65	
WCDMA Band IV	Co	onducted Power(dBm)		
WCDIMA Band IV	Channel 1312	Channel 1413	Channel 1513	
Test Results	22.40	22.40	22.39	

### 3. Test Results

#### 3.1. ANSI C63.19-2007 Limits

Category	Category Telephone RF parameters < 960 MHz					
Near field	AWF	E-field emis	sions	H-field emissions		
Cotogon, M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m	
Category M1/T1	<b>–</b> 5	473.2 to 841.4	V/m	1.43 to 2.54	A/m	
Catagon, M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m	
Category M2/T2	<b>-</b> 5	266.1 to 473.2	V/m	0.80 to 1.43	A/m	
Catagon, M2/T2	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
Category M3/T3	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
Cotomor MA/TA	0	< 199.5	V/m	< 0.60	A/m	
Category M4/T4	<b>–</b> 5	< 149.6	V/m	< 0.45	A/m	
Category		Teleph	one RF parar	neters > 960 MHz	·	
Near field	AWF	E-field emis	sions	H-field emissions		
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
Category W1711	<b>-</b> 5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
Cotogon, M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m	
Category M2/T2	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m	
Catagory M2/T2	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m	
Category M3/T3	<b>-</b> 5	47.3 to 84.1	V/m	0.14 to 0.25	A/m	
Cotogon, MA/T4	0	< 63.1	V/m	< 0.19	A/m	
Category M4/T4	-5	< 47.3	V/m	< 0.14	A/m	

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### 3.2. Summary Test Results

#### **GSM 850 Results**

E-Field with Battery 1						
Channel	Frequency (MHz) Peak Field (V/m) Power Drift (dB) Rating					
High/251	848.8	166.4	-0.031	МЗ	Figure 12	
Middle/190	836.6	174.7	-0.031	МЗ	Figure 13	
Low/128	824.2	178.0	0.004	МЗ	Figure 14	
		E-Field with B	attery 2			
Low/128	824.2	177.5	0.002	МЗ	Figure 15	
		H-Field with B	attery 1			
Channel Frequency (MHz) Peak Field (A/m) Power Drift (dB) Rating Resu						
High/251	848.8	0.232	0.028	M4	Figure 16	
Middle/190	836.6	0.245	0.040	M4	Figure 17	
Low/128	824.2	0.240	0.019	M4	Figure 18	
		H-Field with B	attery 2			
Middle/190	836.6	0.240	-0.003	M4	Figure 19	

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#### **GSM 1900 Results**

	E-Field with Battery 1						
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results		
High/810	1909.8	80.9	0.059	МЗ	Figure 20		
Middle/661	1880	81.1	0.013	МЗ	Figure 21		
Low/512	1850.2	80.0	0.091	МЗ	Figure 22		
	E-Field with Battery 2						
Middle/661	1880	80.6	-0.057	МЗ	Figure 23		
		H-Field with B	attery 1				
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results		
High/810	1909.8	0.225	-0.021	МЗ	Figure 24		
Middle/661	1880	0.249	-0.010	МЗ	Figure 25		
Low/512	1850.2	0.240	0.012	МЗ	Figure 26		
	H-Field with Battery 2						
Middle/661	1880	0.249	-0.008	М3	Figure 27		

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#### **WCDMA Band IV Results**

	E-Field with Battery 1					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results	
High/1513	1752.6	34.1	0.153	M4	Figure 28	
Middle/1413	1732.6	38.3	-0.037	M4	Figure 29	
Low/1312	1712.4	32.9	-0.004	M4	Figure 30	
	E-Field with Battery 2					
Middle/1413	1732.6	39.2	-0.007	M4	Figure 31	
		H-Field with Ba	attery 1			
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results	
High/1513	1752.6	0.095	0.033	M4	Figure 32	
Middle/1413	1732.6	0.109	0.000	M4	Figure 33	
Low/1312	1712.4	0.095	0.012	M4	Figure 34	
	H-Field with Battery 2					
Middle/1413	1732.6	0.109	0.037	M4	Figure 35	

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### 4. Measurement Uncertainty

No.	Error source	Туре	Uncertainty Value (%)	Prob. Dist.	k	c <sub>i/</sub> E	c₁∖H	Standard Uncertainty (%) $u_i^{'}$ (%)	Standard Uncertainty  (%) $u_i^{'}$ (%)  H	Degree of freedom V <sub>eff</sub> or v <sub>i</sub>
		I		Measu	rement	System	)	I		1
1	Probe Calibration	В	5.1	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Test Arch	В	7.2	R	$\sqrt{3}$	1	0	4.1	0	∞
6	Linearity	В	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
7	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
8	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
9	Readout Electronics	В	0.3	N	1	1	1	0.3	0.3	∞
10	Response Time	В	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
11	Integration Time	В	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
12	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
13	RF Reflections	В	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
14	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
15	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
16	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test	Sample Related	•			•	•	•			
17	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
18	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞

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19	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
20	Power Drift	В	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞
			F	hantom	and Set	up rela	ted			
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Com	Combined standard uncertainty (%)					15.19	10.82			
Expa	Expanded Std. uncertainty on power (K=2)					30.38	21.65			
Expa	nded Std. uncertainty or	n field (K	=2)					15.19	10.82	

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### 5. Main Test Instruments

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 11, 2012	One year
02	Power sensor	Agilent N8481H	MY50350004	September 25, 2011	One year
03	Signal Generator	HP 8341B	2730A00804	September 12, 2011	One year
04	Amplifier	IXA-020	0401	No Calibration R	equested
05	BTS	E5515C	MY48360988	December 2, 2011	One year
06	E-Field Probe	ER3DV6	2303	February 21, 2012	One year
07	H-Field Probe	H3DV6	6138	February 21, 2012	One year
08	DAE	DAE4	1317	January 23, 2012	One year
09	Validation Kit 835MHz	CD835V3	1133	February 21, 2012	One year
10	Validation Kit 1880MHz	CD1880V3	1115	February 21, 2012	One year
11	Hygrothermograph	WS-1	64591	September 28, 2011	One year

\*\*\*\*\*END OF REPORT \*\*\*\*\*

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#### **ANNEX A: System Check Results**

HAC\_System Performance Check at 835MHz\_E DUT: Dipole 835 MHz; Type: CD835V3; SN:1133

Date/Time: 4/21/2012 4:29:01 AM

Communication System: CW; Frequency: 835 MHz;Duty Cycle: 1:1 Medium parameters used:  $\sigma$  = 0 mho/m,  $\epsilon_r$  = 1;  $\rho$  = 1000 kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 159.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 135.6 V/m; Power Drift = -0.001 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
153.0 M4	159.1 M4	155.9 M4
Grid 4	Grid 5	Grid 6
91.5 M4	98.0 M4	96.7 M4
Grid 7	Grid 8	Grid 9
171.2 M4	183.0 M4	182.0 M4

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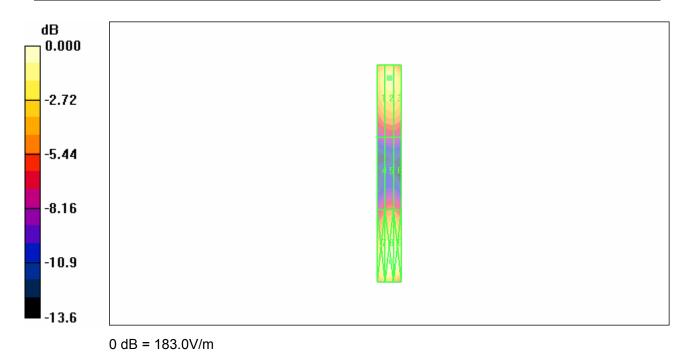


Figure 8 System Performance Check 835MHz\_E

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HAC\_System Performance Check at 835MHz\_H DUT: Dipole 835 MHz; Type: CD835V3; SN: 1133

Date/Time: 4/20/2012 9:37:54 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x381x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.485 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.514 A/m; Power Drift = -0.011 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.420 M4	0.438 M4	0.409 M4
Grid 4	Grid 5	Grid 6
0.465 M4	0.485 M4	0.454 M4
Grid 7	Grid 8	Grid 9
0.386 M4	0.401 M4	0.376 M4

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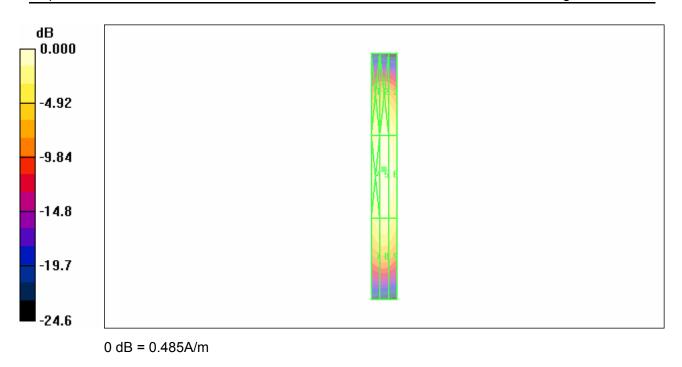


Figure 9 System Performance Check 835MHz\_H

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HAC\_System Performance Check at 1880MHz\_E DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 4/21/2012 4:10:12 AM

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 125.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 157.4 V/m; Power Drift = -0.037 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

#### Peak E-field in V/m

Grid 1	Grid 2	Grid 3
116.8 M2	125.0 M2	123.7 M2
Grid 4	Grid 5	Grid 6
98.5 M3	102.4 M3	98.1 M3
Grid 7	Grid 8	Grid 9
159.5 M2	161.7 M2	153.0 M2

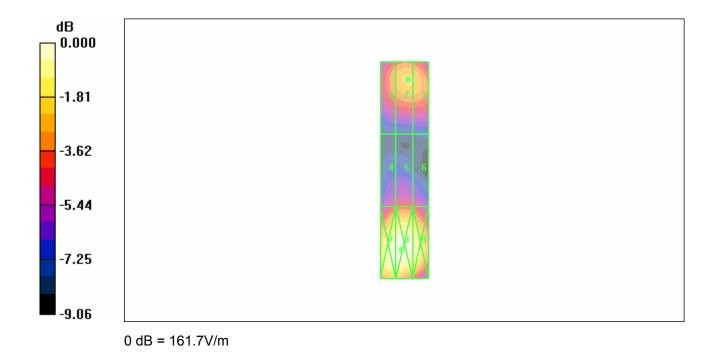


Figure 10 System Performance Check 1880MHz\_E

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HAC\_System Performance Check at 1880MHz\_H DUT: Dipole 1880 MHz; Type: CD1880V3; SN: 1115

Date/Time: 4/20/2012 9:52:42 PM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.456 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.482 A/m; Power Drift = -0.016 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.406 M2	0.419 M2	0.394 M2
Grid 4	Grid 5	Grid 6
0.442 M2	0.456 M2	0.429 M2
Grid 7	Grid 8	Grid 9
0.406 M2	0.421 M2	0.394 M2

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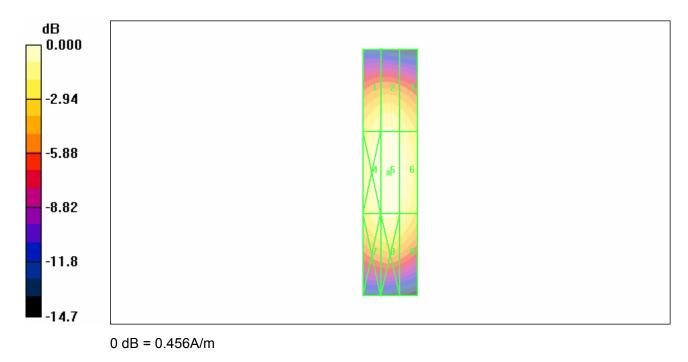


Figure 11 System Performance Check 1880MHz\_H

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#### **ANNEX B: Graph Results**

#### HAC RF E-Field GSM 850 High (Battery 1)

Date/Time: 4/21/2012 5:19:13 AM

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 166.4 V/m

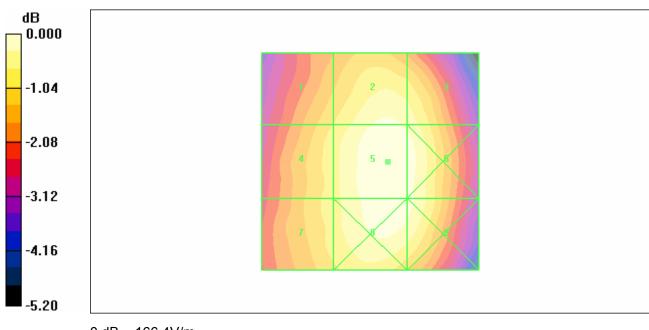
Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 73.7 V/m; Power Drift = -0.031 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

#### Peak E-field in V/m

Grid 1	Grid 2	Grid 3
147.9 M4	161.7 M3	158.4 M3
Grid 4	Grid 5	Grid 6
151.8 M3	166.4 M3	163.6 M3
Grid 7	Grid 8	Grid 9
151.8 M3	164.2 M3	162.2 M3

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0 dB = 166.4V/m

Figure 12 HAC RF E-Field GSM 850 Channel 251

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#### HAC RF E-Field GSM 850 Middle (Battery 1)

Date/Time: 4/21/2012 5:11:50 AM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 174.7 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 77.2 V/m; Power Drift = -0.031 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

#### Peak E-field in V/m

Grid 1	Grid 2	Grid 3
154.7 M3	170.2 M3	166.6 M3
Grid 4	Grid 5	Grid 6
159.6 M3	174.7 M3	171.0 M3
Grid 7	Grid 8	Grid 9
159.2 M3	171.7 M3	169.1 M3

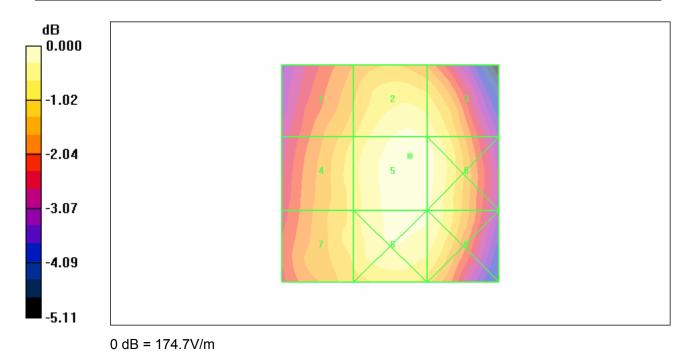


Figure 13 HAC RF E-Field GSM 850 Channel 190

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### HAC RF E-Field GSM 850 Low (Battery 1)

Date/Time: 4/21/2012 5:23:59 AM

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 178.0 V/m

Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 79.0 V/m; Power Drift = 0.004 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

### Peak E-field in V/m

Grid 1	Grid 2	Grid 3
158.8 M3	173.8 M3	170.7 M3
Grid 4	Grid 5	Grid 6
163.1 M3	178.0 M3	174.9 M3
Grid 7	Grid 8	Grid 9
160.8 M3	175.2 M3	172.7 M3

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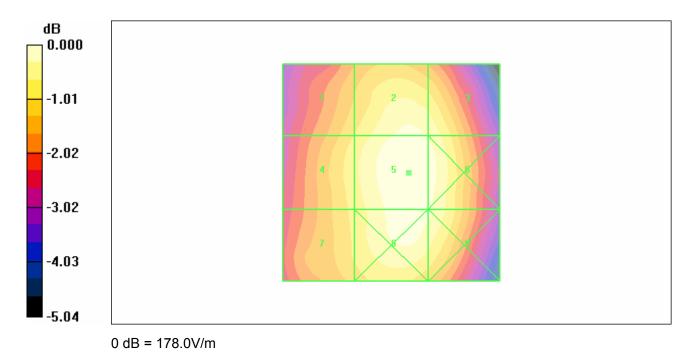


Figure 14 HAC RF E-Field GSM 850 Channel 128

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### HAC RF E-Field GSM 850 Low (Battery 2)

Date/Time: 4/21/2012 5:32:38 AM

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 177.5 V/m

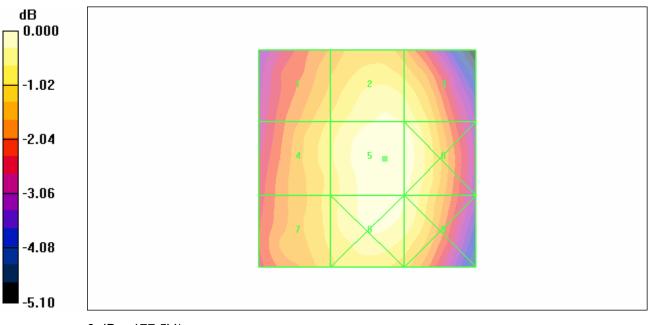
Probe Modulation Factor = 2.81

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 78.9 V/m; Power Drift = 0.002 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

### Peak E-field in V/m

Grid 1	Grid 2	Grid 3
159.2 M3	172.5 M3	169.9 M3
Grid 4	Grid 5	Grid 6
163.0 M3	177.5 M3	175.2 M3
Grid 7	Grid 8	Grid 9
161.3 M3	175.4 M3	171.9 M3

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0 dB = 177.5V/m

Figure 15 HAC RF E-Field GSM 850 Channel 128

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### HAC RF H-Field GSM 850 High (Battery 1)

Date/Time: 4/21/2012 6:25:27 PM

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.232 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.067 A/m; Power Drift = 0.028 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.320 M4	0.232 M4	0.144 M4
Grid 4	Grid 5	Grid 6
0.311 M4	0.227 M4	0.146 M4
Grid 7	Grid 8	Grid 9
0.315 M4	0.232 M4	0.151 M4

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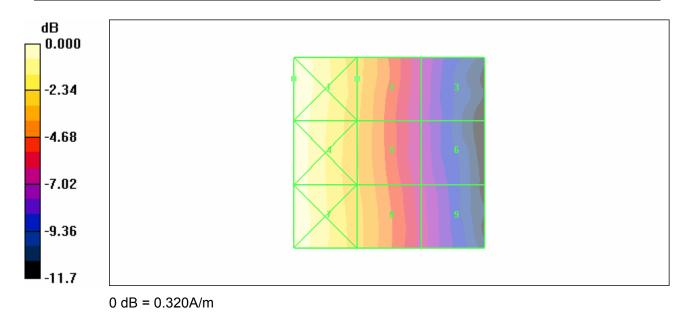


Figure 16 HAC RF H-Field GSM 850Channel 251

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## HAC RF H-Field GSM 850 Middle (Battery 1)

Date/Time: 4/21/2012 6:15:36 PM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.240 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.069 A/m; Power Drift = 0.019 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.331 M4	0.236 M4	0.147 M4
Grid 4	Grid 5	Grid 6
0.324 M4	0.234 M4	0.147 M4
Grid 7	Grid 8	Grid 9
0.329 M4	0.240 M4	0.159 M4

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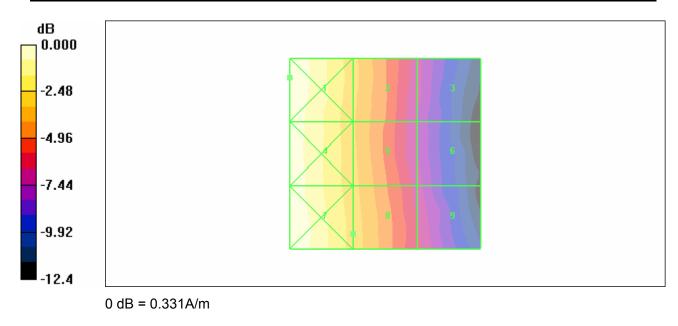


Figure 17 HAC RF H-Field GSM 850 Channel 190

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## HAC RF H-Field GSM 850 Low (Battery 1)

Date/Time: 4/21/2012 6:20:26 PM

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

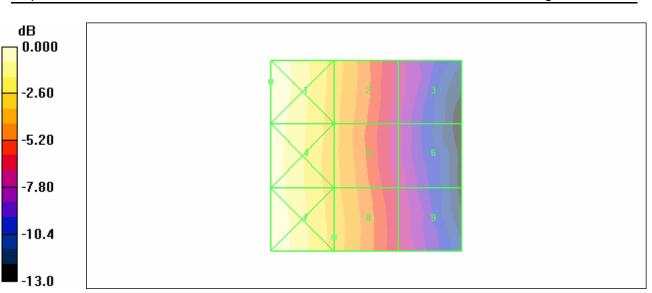
Maximum value of peak Total field = 0.245 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.070 A/m; Power Drift = 0.040 dB **Hearing Aid Near-Field Category: M4 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.343 M4	0.244 M4	0.149 M4
Grid 4	Grid 5	Grid 6
0.334 M4	0.239 M4	0.150 M4
Grid 7	Grid 8	Grid 9
0.339 M4	0.245 M4	0.159 M4

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0 dB = 0.343A/m

Figure 18 HAC RF H-Field GSM 850 Channel 128

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### HAC RF H-Field GSM 850 Middle (Battery 2)

Date/Time: 4/21/2012 6:31:34 PM

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.240 A/m

Probe Modulation Factor = 2.75

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.068 A/m; Power Drift = -0.003 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.328 M4	0.236 M4	0.148 M4
Grid 4	Grid 5	Grid 6
0.322 M4	0.233 M4	0.145 M4
Grid 7	Grid 8	Grid 9
0.327 M4	0.240 M4	0.155 M4

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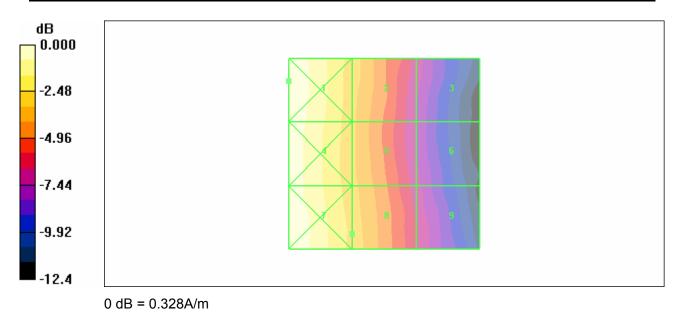


Figure 19 HAC RF H-Field GSM 850 Channel 190

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## HAC RF E-Field GSM 1900 High (Battery 1)

Date/Time: 4/21/2012 5:43:18 AM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 80.9 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 21.6 V/m; Power Drift = 0.059 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
73.6 M3	61.4 M3	49.6 M3
Grid 4	Grid 5	Grid 6
55.6 M3	80.7 M3	80.9 M3
Grid 7	Grid 8	Grid 9
88.2 M2	98.9 M2	95.9 M2

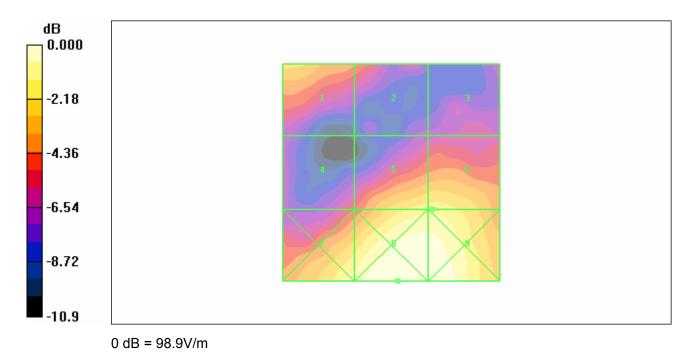


Figure 20 HAC RF E-Field GSM 1900 Channel 810

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### HAC RF E-Field GSM 1900 Middle (Battery 1)

Date/Time: 4/21/2012 1:44:28 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle 2 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 81.1 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 22.7 V/m; Power Drift = 0.013 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
77.6 M3	60.6 M3	64.5 M3
Grid 4	Grid 5	Grid 6
58.8 M3	81.1 M3	80.5 M3
Grid 7	Grid 8	Grid 9
90.2 M2	96.7 M2	96.1 M2

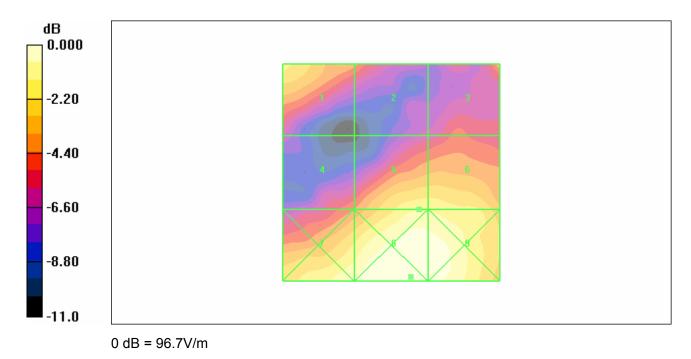


Figure 21 HAC RF E-Field GSM 1900 Channel 661

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### HAC RF E-Field GSM 1900 Low (Battery 1)

Date/Time: 4/21/2012 1:52:24 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 80.0 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 23.8 V/m; Power Drift = 0.091 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
70.0 M3	53.7 M3	50.2 M3
Grid 4	Grid 5	Grid 6
59.5 M3	80.0 M3	80.0 M3
Grid 7	Grid 8	Grid 9
88.0 M2	98.8 M2	95.6 M2

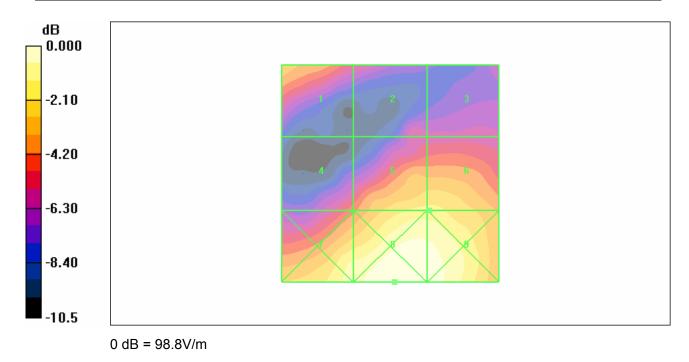


Figure 22 HAC RF E-Field GSM 1900 Channel 512

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### HAC RF E-Field GSM 1900 Middle (Battery 2)

Date/Time: 4/21/2012 2:11:23 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 80.6 V/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 22.8 V/m; Power Drift = -0.057 dB Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
78.0 M3	55.0 M3	52.1 M3
Grid 4	Grid 5	Grid 6
58.3 M3	80.6 M3	80.6 M3
Grid 7	Grid 8	Grid 9
89.1 M2	100.5 M2	96.5 M2

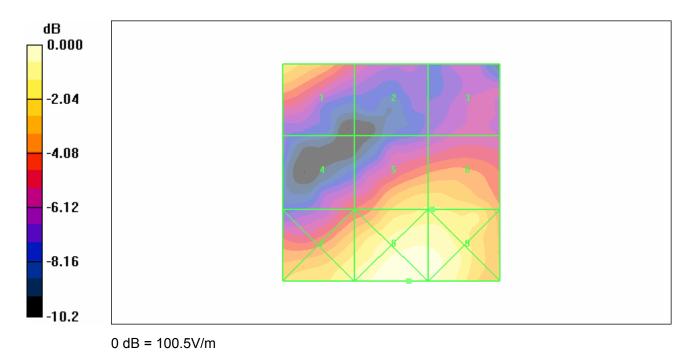


Figure 23 HAC RF E-Field GSM 1900 Channel 661

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## HAC RF H-Field GSM 1900 High (Battery 1)

Date/Time: 4/21/2012 6:00:00 PM

Communication System: PCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3 °C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.225 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.082 A/m; Power Drift = -0.021 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.221 M3	0.221 M3	0.189 M3
Grid 4	Grid 5	Grid 6
0.237 M3	0.225 M3	0.189 M3
Grid 7	Grid 8	Grid 9
0.275 M2	0.223 M3	0.168 M3

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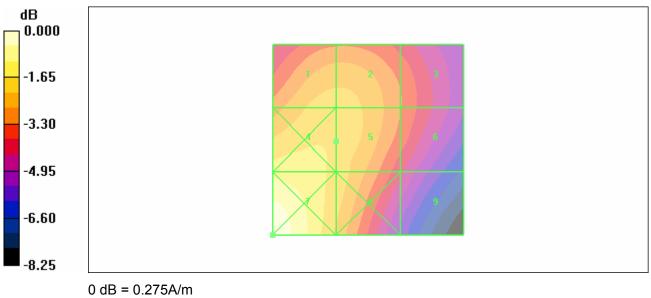


Figure 24 HAC RF H-Field GSM 1900 Channel 810

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## HAC RF H-Field GSM 1900 Middle (Battery 1)

Date/Time: 4/21/2012 5:53:31 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle 2 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.249 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.092 A/m; Power Drift = -0.010 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.247 M3	0.247 M3	0.213 M3
Grid 4	Grid 5	Grid 6
0.253 M2	0.249 M3	0.213 M3
Grid 7	Grid 8	Grid 9
0.290 M2	0.243 M3	0.184 M3

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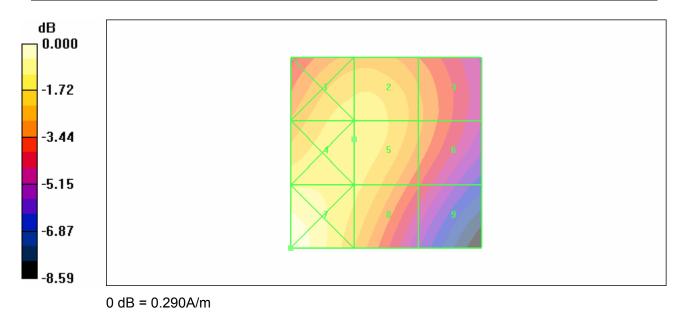


Figure 25 HAC RF H-Field GSM 1900 Channel 661

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### HAC RF H-Field GSM 1900 Low (Battery 1)

Date/Time: 4/21/2012 4:20:41 PM

Communication System: PCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3 °C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.240 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.092 A/m; Power Drift = 0.012 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.229 M3	0.233 M3	0.214 M3
Grid 4	Grid 5	Grid 6
0.243 M3	0.240 M3	0.214 M3
Grid 7	Grid 8	Grid 9
0.299 M2	0.242 M3	0.193 M3

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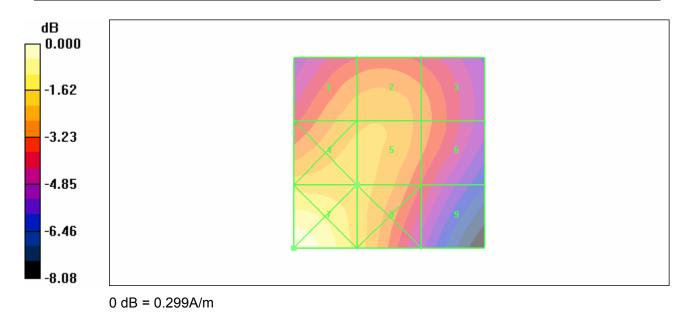


Figure 26 HAC RF H-Field GSM 1900 Channel 512

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## HAC RF H-Field GSM 1900 Middle (Battery 2)

Date/Time: 4/21/2012 6:06:47 PM

Communication System: PCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.249 A/m

Probe Modulation Factor = 2.84

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.092 A/m; Power Drift = -0.008 dB **Hearing Aid Near-Field Category: M3 (AWF -5 dB)** 

Grid 1	Grid 2	Grid 3
0.247 M3	0.247 M3	0.214 M3
Grid 4	Grid 5	Grid 6
0.253 M2	0.249 M3	0.214 M3
Grid 7	Grid 8	Grid 9
0.291 M2	0.242 M3	0.185 M3

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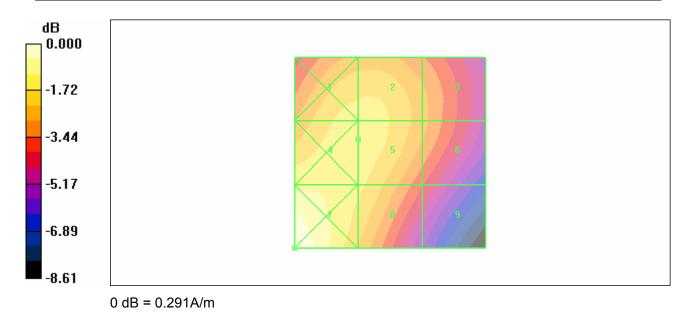


Figure 27 HAC RF H-Field GSM 1900 Channel 661

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### **HAC RF E-Field WCDMA Band IV High (Battery 1)**

Date/Time: 4/21/2012 3:03:30 PM

Communication System: WCDMA Band IV; Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device High/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 34.1 V/m

Probe Modulation Factor = 1.02

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 26.1 V/m; Power Drift = 0.153 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
29.3 M4	22.5 M4	22.1 M4
Grid 4	Grid 5	Grid 6
24.4 M4	34.1 <b>M</b> 4	34.1 M4
Grid 7	Grid 8	Grid 9
37.6 M4	43.7 <b>M</b> 4	41.8 <b>M</b> 4

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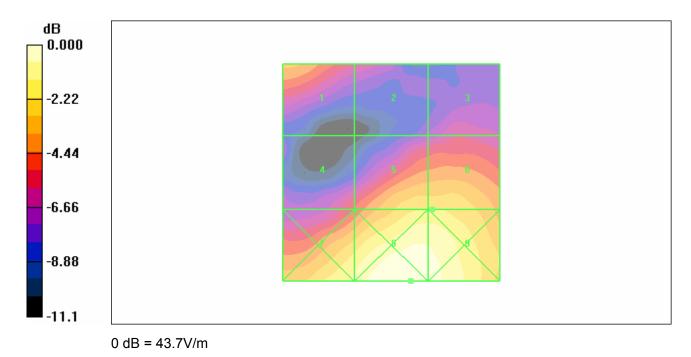


Figure 28 HAC RF E-Field WCDMA Band IV Channel 1513

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### HAC RF E-Field WCDMA Band IV Middle (Battery 1)

Date/Time: 4/21/2012 2:57:50 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

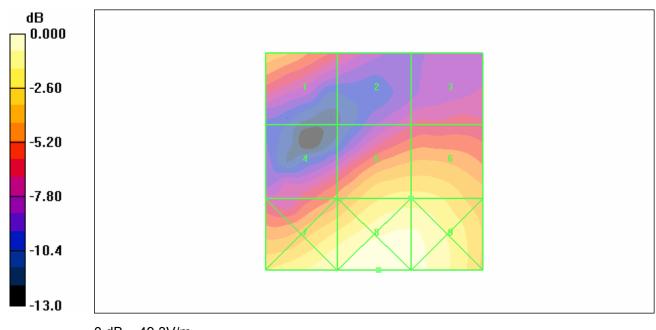
Maximum value of peak Total field = 38.3 V/m

Probe Modulation Factor = 1.02

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 31.0 V/m; Power Drift = -0.037 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
32.0 M4	23.6 M4	23.4 <b>M</b> 4
Grid 4	Grid 5	Grid 6
28.2 M4	38.3 M4	38.3 M4
Grid 7	Grid 8	Grid 9
44.2 M4	49.3 M4	46.7 M4



0 dB = 49.3V/m

Figure 29 HAC RF E-Field WCDMA Band IV Channel 1413

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#### **HAC RF E-Field WCDMA Band IV Low (Battery 1)**

Date/Time: 4/21/2012 3:08:39 PM

Communication System: WCDMA Band IV; Frequency: 1712.4 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3 ℃ Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 32.9 V/m

Probe Modulation Factor = 1.02

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 26.6 V/m; Power Drift = -0.004 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
28.1 M4	20.3 M4	20.6 M4
Grid 4	Grid 5	Grid 6
24.3 M4	32.9 M4	32.9 M4
Grid 7	Grid 8	Grid 9
39.3 M4	42.5 M4	40.7 M4

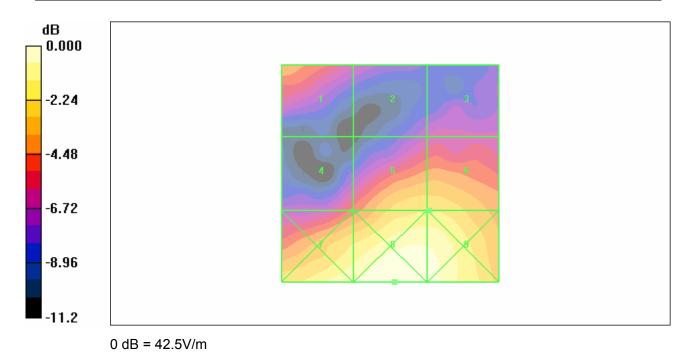


Figure 30 HAC RF E-Field WCDMA Band IV Channel 1312

### HAC RF E-Field WCDMA Band IV Middle (Battery 2)

Date/Time: 4/21/2012 3:18:37 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2303; ConvF(1, 1, 1); Calibrated: 2/21/2012

Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 39.2 V/m

Probe Modulation Factor = 1.02

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 31.1 V/m; Power Drift = -0.007 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
32.3 M4	23.2 M4	23.8 M4
Grid 4	Grid 5	Grid 6
28.6 M4	39.2 <b>M</b> 4	39.2 M4
Grid 7	Grid 8	Grid 9
44.8 M4	49.2 M4	47.4 M4

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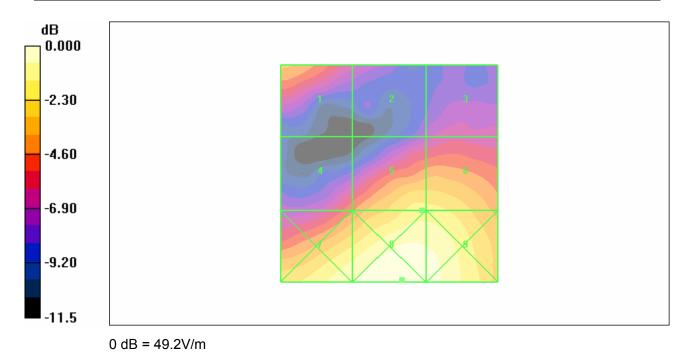


Figure 31 HAC RF E-Field WCDMA Band IV Channel 1413

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#### **HAC RF H-Field WCDMA Band IV High (Battery 1)**

Date/Time: 4/21/2012 3:42:41 PM

Communication System: WCDMA Band IV; Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device High/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.095 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.103 A/m; Power Drift = 0.033 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.091 M4	0.094 M4	0.088 M4
Grid 4	Grid 5	Grid 6
0.095 M4	0.095 M4	0.088 M4
Grid 7	Grid 8	Grid 9
0.117 M4	0.096 M4	0.080 M4

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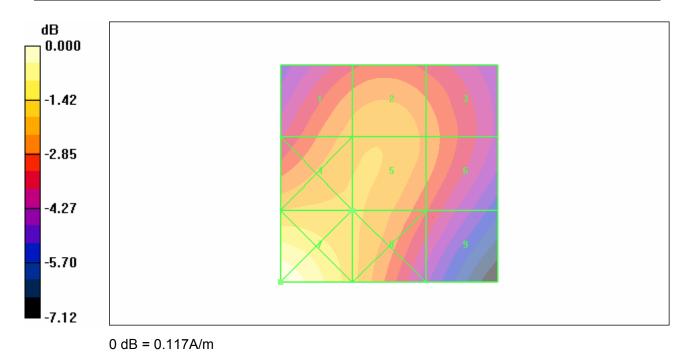


Figure 32 HAC RF H-Field WCDMA Band IV Channel 1513

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#### **HAC RF H-Field WCDMA Band IV Middle (Battery 1)**

Date/Time: 4/21/2012 3:32:10 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.109 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.118 A/m; Power Drift = 0.000 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.106 M4	0.108 M4	0.098 M4
Grid 4	Grid 5	Grid 6
0.110 M4	0.109 M4	0.099 M4
Grid 7	Grid 8	Grid 9
0.133 M4	0.108 M4	0.091 M4

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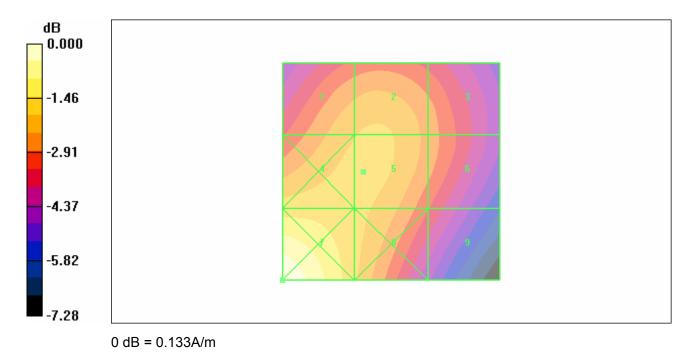


Figure 33 HAC RF H-Field WCDMA Band IV Channel 1413

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#### **HAC RF H-Field WCDMA Band IV Low (Battery 1)**

Date/Time: 4/21/2012 3:37:26 PM

Communication System: WCDMA Band IV; Frequency: 1712.4 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Low/Hearing Aid Compatibility

**Test (101x101x1):** Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.095 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.104 A/m; Power Drift = 0.012 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.093 M4	0.094 M4	0.087 M4
Grid 4	Grid 5	Grid 6
0.097 M4	0.095 M4	0.087 M4
Grid 7	Grid 8	Grid 9
0.116 M4	0.095 M4	0.080 M4

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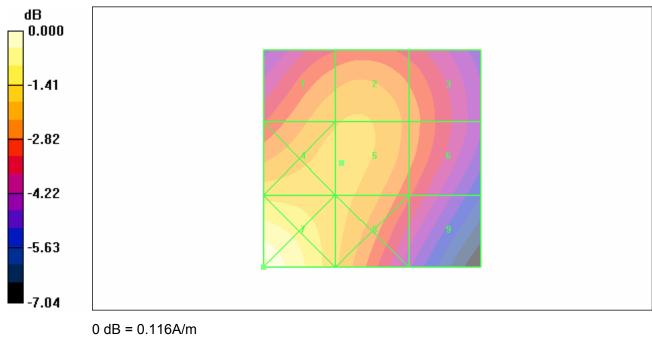


Figure 34 HAC RF H-Field WCDMA Band IV Channel 1312

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#### HAC RF H-Field WCDMA Band IV Middle (Battery 2)

Date/Time: 4/21/2012 3:54:50 PM

Communication System: WCDMA Band IV; Frequency: 1732.6 MHz; Duty Cycle: 1:1

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Ambient Temperature:22.3  $^{\circ}$ C Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6138; ; Calibrated: 2/21/2012 Electronics: DAE4 Sn1317; Calibrated: 1/23/2012 Phantom: HAC Test Arch; Type: SD HAC P01 BA

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

#### H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device Middle/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.109 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.119 A/m; Power Drift = 0.037 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)** 

#### Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.107 M4	0.108 M4	0.099 M4
Grid 4	Grid 5	Grid 6
0.111 M4	0.109 M4	0.100 M4
Grid 7	Grid 8	Grid 9
0.134 M4	0.109 M4	0.091 M4

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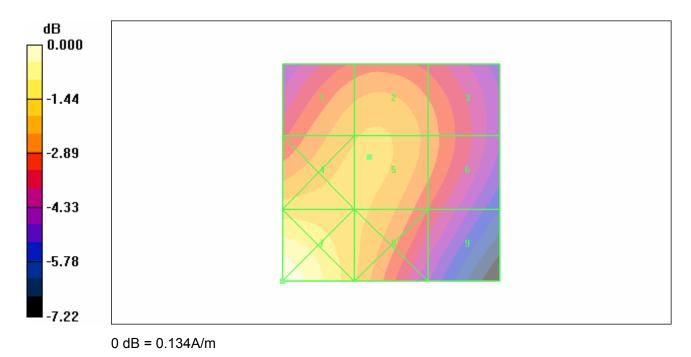


Figure 35 HAC RF H-Field WCDMA Band IV Channel 1413

#### **ANNEX C: E-Probe Calibration Certificate**

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst S Service suisse d'étalonnage Servizio svizzero di taratura

Swiss Calibration Service

Accreditation No.: SCS 108

C

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

TA Shanghai (Auden)

Certificate No: ER3-2303 Feb12

#### CALIBRATION CERTIFICATE

Object

ER3DV6 - SN:2303

Calibration procedure(s)

QA CAL-02.v6, QA CAL-25.v4

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

February 21, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI): The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

ID	Cal Date (Certificate No.)	Scheduled Calibration
GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
MY41496087	31-Mar-11 (No. 217-01372)	Apr-12
SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
SN: S5088 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12
SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13 +
ID	Check Date (in house)	Scheduled Check
US3642U01700 *	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12
	G841293874 MY41496087 SN: S6054 (3c) SN: S5086 (20b) SN: S5129 (30b) SN: 2328 SN: 789	GB41293874   31-Mar-11 (No. 217-01372)     MY41496067   31-Mar-11 (No. 217-01372)     SN: S5054 (3c)   29-Mar-11 (No. 217-01369)     SN: S5086 (20b)   29-Mar-11 (No. 217-01367)     SN: S5129 (30b)   29-Mar-11 (No. 217-01370)     SN: 2328   11-Ocl-11 (No. ER3-2328_Oct11)     SN: 789   30-Jan-12 (No. DAE4-789_Jan12)     ID   Check Date (in house)     US3642U01700   4-Aug-99 (in house check Apr-11)

Name Function Calibrated by Claudio Leubler Laboratory Technician Katja Pokovic Technical Manager Approved by:

ssued: February 22, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: ER3-2303 Feb12

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Report No. RXA1204-0050HAC01

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

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Glossary:

NORMx,y,z

sensitivity in free space

DCP

diode compression point

CF A, B, C crest factor (1/duty\_cycle) of the RF signal modulation dependent linearization parameters

Polarization o

o rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

#### Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, \* IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

#### Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization § = 0 for XY sensors and § = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z \* frequency\_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe-tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

February 21, 2012

# Probe ER3DV6

SN:2303

Manufactured:

November 6, 2002

Calibrated:

February 21, 2012

Calibrated for DASY/EASY Systems

(Note: non-compatible with DASY2 system!)

February 21, 2012

### DASY/EASY - Parameters of Probe: ER3DV6 - SN:2303

#### **Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (µV/(V/m) <sup>2</sup> )	1.40	1.42	1.43	± 10.1 %
DCP (mV) <sup>8</sup>	100.7	99.2	104.7	

#### **Modulation Calibration Parameters**

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc <sup>E</sup> (k=2)
10000 CW	CW 0.00	X	0.00	0.00	1.00	111.4	±3.0 %	
			Y	0.00	0.00	1.00	139.9	
			Z	0.00	0.00	1.00	133.1	

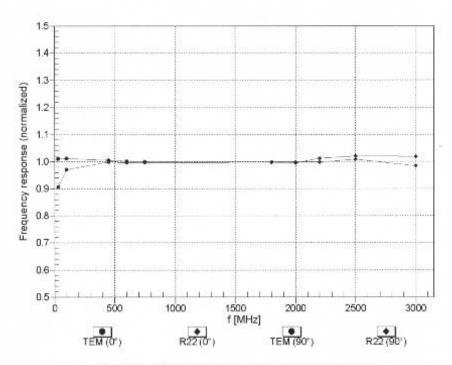
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Numerical linearization parameter: uncertainty not required.
 Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

February 21, 2012

## Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

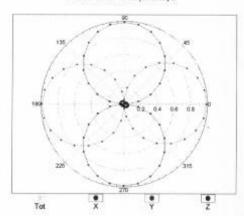
February 21, 2012

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

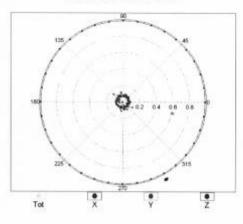
136 48 0.4 0.6 0.6 0.6 Tot X Y Z

f=2500 MHz,R22,0°

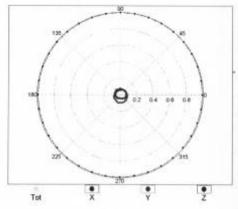


## Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$

f=600 MHz,TEM,90°

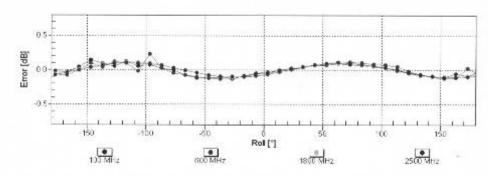


f=2500 MHz,R22,90°



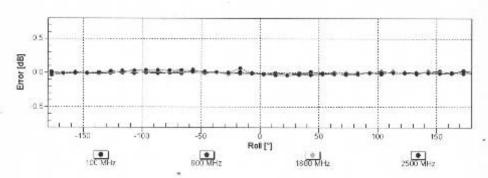
February 21, 2012

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

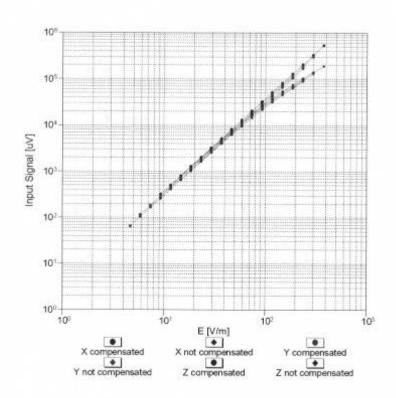
## Receiving Pattern (\$\phi\$), 9 = 90°

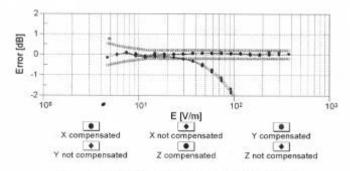


Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

February 21, 2012

#### Dynamic Range f(E-field) (TEM cell , f = 900 MHz)



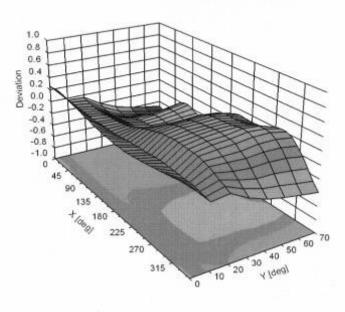


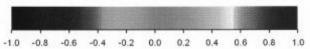
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

February 21, 2012

## Deviation from Isotropy in Air

Error (¢, 9), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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ER3DV6-- SN:2303

February 21, 2012

#### DASY/EASY - Parameters of Probe: ER3DV6 - SN:2303

#### Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (*)	-156.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Certificate No: ER3-2303\_Feb12

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#### **ANNEX D: H-Probe Calibration Certificate**

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Client

TA Shanghai (Auden)

Certificate No: H3-6138\_Feb12

Accreditation No.: SCS 108

#### CALIBRATION CERTIFICATE

Object

H3DV6 - SN:6138

Calibration procedure(s)

QA CAL-03.v6, QA CAL-25.v4

Calibration procedure for H-field probes optimized for close near field

evaluations in air

Calibration date:

February 21, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

ID	Cal Date (Certificate No.)	Scheduled Calibration
GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
ID .	Check Date (in house)	Scheduled Check
US3642U01700 =	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12
	GB41293874 MY41498087 SN: S5054 (3c) SN: S5086 (20b) SN: S5129 (30b) SN: 6182 SN: 789	GB41293874   31-Mar-11 (No. 217-01372)     MY41498087   31-Mar-11 (No. 217-01372)     SN: S5054 (3c)   29-Mar-11 (No. 217-01369)     SN: S5086 (20b)   29-Mar-11 (No. 217-01367)     SN: S5129 (30b)   29-Mar-11 (No. 217-01370)     SN: 6182   11-Oct-11 (No. H3-6182_Oct11)     SN: 789   30-Jan-12 (No. DAE4-789_Jan12)     ID   Check Date (in house)     US3642U01700   4-Aug-99 (in house check Apr-11)

Calibrated by:

Claudio Leubler

Claudio Leubler

Laboratory Technician

Approved by:

Katja Pokovic

Technical Manager

Issued: February 23, 2012

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Certificate No: H3-6138\_Feb12

Report No. RXA1204-0050HAC01

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#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

#### Glossary:

NORMx,y,z DCP CF sensitivity in free space diode compression point

CF A, B, C

crest factor (1/duty\_cycle) of the RF signal modulation dependent linearization parameters

Polarization φ

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

#### Calibration is Performed According to the Following Standards:

 IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

#### Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- X,Y,Z(f)\_a0a1a2= X,Y,Z\_a0a1a2\* frequency\_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics.
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X\_a0a1a2 (no uncertainty required).

Certificate No: H3-6138\_Feb12

H3DV6 - SN:6138

February 21, 2012

# Probe H3DV6

SN:6138

Manufactured:

July 3, 2002

Calibrated:

February 21, 2012

Calibrated for DASY/EASY Systems

(Note: non-compatible with DASY2 system!)

H3DV6-SN:6138

February 21, 2012

## DASY/EASY - Parameters of Probe: H3DV6 - SN:6138

#### **Basic Calibration Parameters**

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(mV))	a0	2.73E-003	2.93E-003	3.18E-003	± 5.1 %
Norm (A/m / √(mV))	a1	-5.89E-005	-2.38E-004	-2.18E-004	± 5.1 %
Norm (A/m / √(mV))	a2	-5.50E-006	-3.95E-006	-8.28E-007	± 5.1 %
DCP (mV) <sup>8</sup>	-	93.5	92.1	94.8	

#### Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc <sup>b</sup> (k=2)
10000	000 CW 0.00	X	0.00	0.00	1.00	130.7	±3.3 %	
			Y	0.00	0.00	1.00	125.5	
			Z	0.00	0.00	1.00	133.0	

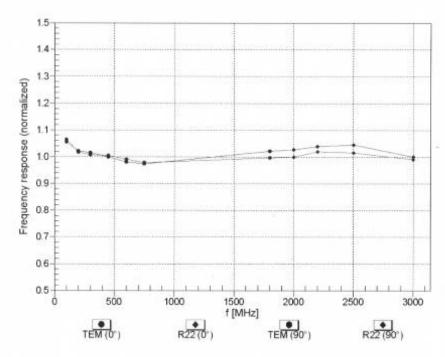
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

<sup>&</sup>lt;sup>6</sup> Numerical linearization parameter: uncertainty not required.
<sup>6</sup> Uncertainty is determined using the max, deviation from linear response applying rectangular distribution and is expressed for the square of the

H3DV6- SN:6138

February 21, 2012

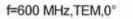
# Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)

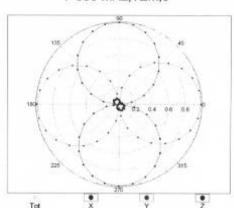


Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

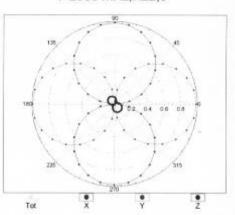
H3DV6- SN:6138 February 21, 2012

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



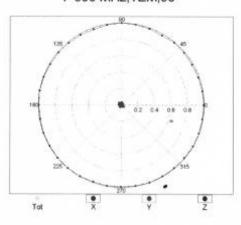


f=2500 MHz,R22,0°

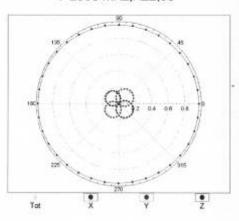


## Receiving Pattern (\$\phi\$), \$\partial = 90°

f=600 MHz,TEM,90°



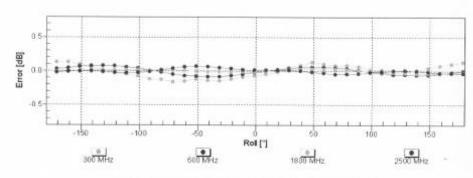
f=2500 MHz,R22,90°



H3DV6-SN:6138

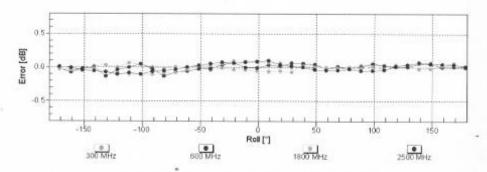
February 21, 2012

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

## Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$

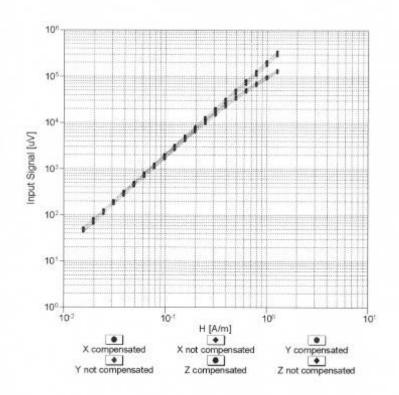


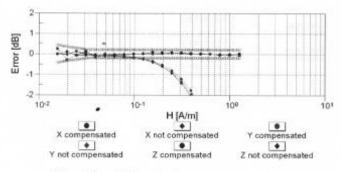
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

H3DV6- SN:6138

February 21, 2012

#### Dynamic Range f(H-field) (TEM cell, f = 900 MHz)



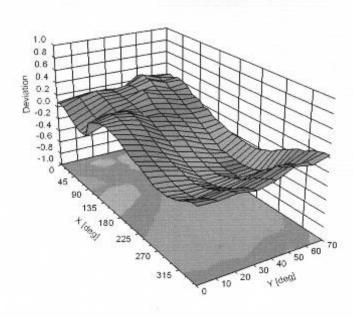


Uncertainty of Linearity Assessment: ± 0.6% (k=2)



#### February 21, 2012

#### Deviation from Isotropy in Air Error (ø, 8), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

H3DV6-SN:6138

February 21, 2012

### DASY/EASY - Parameters of Probe: H3DV6 - SN:6138

#### Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	168.6
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

Certificate No: H3-6138\_Feb12

## **ANNEX E: CD835V3 Dipole Calibration Certificate**

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Client

TA Shanghai (Auden)

Certificate No: CD835V3-1133 Feb12

Accreditation No.: SCS 108

Object	CD835V3 - SN:	1133	
Calibration procedure(s)	QA CAL-20.v6 Calibration proc	edure for dipoles in air	
Calibration date:	February 21, 20	12	
The measurements and the unc	ertainties with confidence	tional standards, which realize the physical uni probability are given on the following pages an bry facility: environment temperature (22 ± 3)°C	d are part of the certificate.
Calibration Equipment used (M&	TE critical for calibration)		
2.3	TE critical for calibration)	Cal Date (Certificate No.)	Scheduled Calibration
Primary Standards	¥	Cal Date (Certificate No.) 05-Oct-11 (No. 217-01451)	Scheduled Calibration Oct-12
Primary Standards Power meter EPM-442A	ID #	- The state of the	
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6	ID # GB37480704 US37292783 SN: 2336	05-Oct-11 (No. 217-01451)	Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6	ID # GB37480704 US37292783 SN: 2336 SN: 6065	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11)	Oct-12 Oct-12 Dec-12 Dec-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6	ID # GB37480704 US37292783 SN: 2336	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11)	Oct-12 Oct-12 Dec-12
Calibration Equipment used (M8 Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards	ID # GB37480704 US37292783 SN: 2336 SN: 6065	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11)	Oct-12 Oct-12 Dec-12 Dec-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B	ID #  GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781  ID #  SN: GB42420191	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H	ID # GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: 3318A09450	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11) Check Date (In house) 09-Oct-09 (In house check Oct-11) 09-Oct-09 (In house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12 In house check: Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A	ID # GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: 3318A09450 SN: US37295597	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (In house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12 In house check: Oct-12 In house check: Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E	ID #  GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781  ID #  SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (In house)  09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11) 18-Oct-01 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E	ID # GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: 3318A09450 SN: US37295597	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (In house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12 In house check: Oct-12 In house check: Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E RF generator E4433B	ID # GB37480704 US37292793 SN: 2336 SN: 6065 SN: 781  ID # SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585 MY 41000675	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (In house)  09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11) 18-Oct-01 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12
Primary Standards Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E	ID # GB37480704 US37292793 SN: 2336 SN: 6065 SN: 781  ID # SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585 MY 41000675	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (in house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11) 18-Oct-01 (in house check Oct-11) 18-Oct-01 (in house check Oct-11) 03-Nov-04 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12  Scheduled Check In house check: Oct-12 In house check: Oct-13

Certificate No: CD835V3-1133\_Feb12

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service sulsse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

#### References

[1] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
   In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
  antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
  maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
  calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
  feed point.

#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.0
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.456 A / m ± 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	161.4 V / m
Maximum measured above low end	100 mW input power	160.0 V / m
Averaged maximum above arm	100 mW input power	160.7 V / m ± 12.8 % (k=2)

#### Appendix

#### **Antenna Parameters**

Frequency	Return Loss	Impedance
800 MHz	15.7 dB	42.6 Ω - 13.5 μΩ
835 MHz	25.2 dB	$47.3 \Omega + 4.7 j\Omega$
900 MHz	17.9 dB	52.9 Ω - 12.8 ]Ω
950 MHz	20,7 dB	46.3 Ω + 8.2 jΩ -
960 MHz	15.5 dB	52.8 Ω + 17.3 jΩ
ALCOHOLOGICAL CONTRACTOR CONTRACT		THE RESERVE THE PARTY OF THE PA

#### 3.2 Antenna Design and Handling

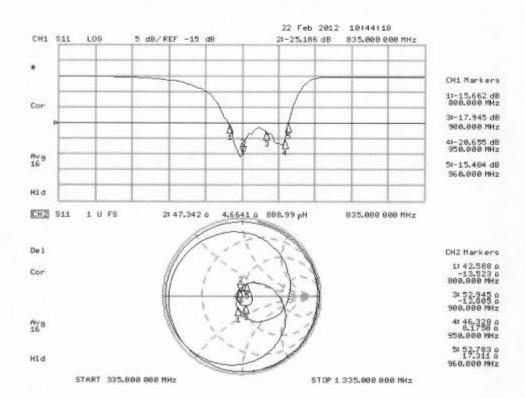
The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.





#### **DASY5 H-field Result**

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

#### DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1133

Communication System: CW; Frequency: 835 MHz Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY52 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- · Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

## Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.49 V/m; Power Drift = 0.00 dB

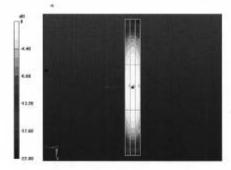
PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.46 A/m

Near-field category: M4 (AWF 0 dB)

PMF scaled H-field

Grid 1 M4 0.38 A/m	
Grid 4 M4 0.43 A/m	
Grid 7 M4 0.37 A/m	



0 dB = 0.46A/m = -6.74 dB A/m

#### **DASY5 E-field Result**

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

#### DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1133

Communication System: CW; Frequency: 835 MHz

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

#### Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

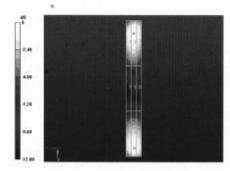
Device Reference Point: 0, 0, -6.3 mm Reference Value = 104.5 V/m; Power Drift = 0.00 dB PMR not calibrated PMF = 1.000 is applied.

E-field emissions = 161.4 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
156.3 V/m	161.4 V/m	157.3 V/m
Grid 4 M4 86.05 V/m		
Grid 7 M4	Grid 8 M4	Grid 9 M4
151.4 V/m	160.0 V/m	157.8 V/m



0 dB = 161.4V/m = 44.16 dB V/m

### **ANNEX F: CD1880V3 Dipole Calibration Certificate**

Calibration Laboratory of Schmid & Partner

Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

TA Shanghai (Auden)

Certificate No: CD1880V3-1115\_Feb12

Accreditation No.: SCS 108

CALIBRATION CERTIFICATE

Object	CD1880V3 - SN	1: 1115	
Calibration procedure(s)	QA CAL-20.v6 Calibration proc	edure for dipoles in air	-
Calibration date:	February 21, 20	12	
The measurements and the unc	ertainties with confidence ucted in the closed laborate	fional standards, which realize the physical uni probability are given on the following pages an ory facility: environment temperature $(22 \pm 3)^{\circ}$ C	d are part of the certificate.
Primary Standards	ID#	Cal Data (Cadificate No.)	400000000000000000000000000000000000000
			Scheduled Calibration
	GB37480704	Cal Date (Certificate No.) 05-Oct-11 (No. 217-01451)	Scheduled Calibration Oct-12
Power meter EPM-442A			
Power meter EPM-442A Power sensor HP 8481A	GB37480704	05-Oct-11 (No. 217-01451)	Oct-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6	GB37480704 US37292783	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451)	Oct-12 Oct-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6	GB37480704 US37292783 SN: 2336	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11)	Oct-12 Oct-12 Dec-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4	GB37480704 US37292783 SN: 2336 SN: 6065	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11)	Oct-12 Oct-12 Dec-12 Dec-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11) Check Date (in house)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11) Check Date (in house) 09-Oct-09 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781  ID # SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11) Check Date (in house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12 In house check: Oct-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: 3318A09450 SN: US37295597	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (in house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12 In house check: Oct-12 In house check: Oct-12
Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781  ID # SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (in house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11) 18-Oct-01 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12 Scheduled Check In house check: Oct-12
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Power meter EPM-442A Power sensor HP 8481A Probe ER3DV6 Probe H3DV6 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP 8482H Power sensor HP 8482A Network Analyzer HP 8753E RF generator E4433B	GB37480704 US37292783 SN: 2336 SN: 6065 SN: 781  ID # SN: GB42420191 SN: 3318A09450 SN: US37295597 US37390585 MY 41000675  Name	05-Oct-11 (No. 217-01451) 05-Oct-11 (No. 217-01451) 29-Dec-11 (No. ER3-2336_Dec11) 29-Dec-11 (No. H3-6065_Dec11) 20-Apr-11 (No. DAE4-781_Apr11)  Check Date (in house) 09-Oct-09 (in house check Oct-11) 09-Oct-09 (in house check Oct-11) 18-Oct-01 (in house check Oct-11) 18-Oct-01 (in house check Oct-11) 03-Nov-04 (in house check Oct-11)	Oct-12 Oct-12 Dec-12 Dec-12 Apr-12  Scheduled Check In house check: Oct-12 In house check: Oct-12 In house check: Oct-12 In house check: Oct-12 In house check: Oct-13

Certificate No: CD1880V3-1115\_Feb12

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## TA Technology (Shanghai) Co., Ltd. Test Report

Report No. RXA1204-0050HAC01

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

## Accreditation No.: SCS 108

#### References

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   In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
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  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (In z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
  antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
  maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
  calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
  feed point.

#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.0
Extrapolation	Advanced Extrapolation	
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1880MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW input power	0.473 A / m ± 8.2 % (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	143.4 V / m
Maximum measured above low end	100 mW input power	139.6 V / m
Averaged maximum above arm	100 mW input power	141.5 V / m ± 12.8 % (k=2)

## **Appendix**

#### **Antenna Parameters**

Frequency	Return Loss	Impedance
1730 MHz	30.5 dB	52.6 Ω + 1.5 jΩ
1880 MHz	21.7 dB	46.1 Ω + 6.9 jΩ
1900 MHz	22.0 dB	$47.6 \Omega + 7.4 j\Omega$
1950 MHz	29.8 dB	49.9 Ω + 3.2 jΩ -
2000 MHz	18.9 dB	41.3 Ω + 5.6 jΩ

#### 3.2 Antenna Design and Handling

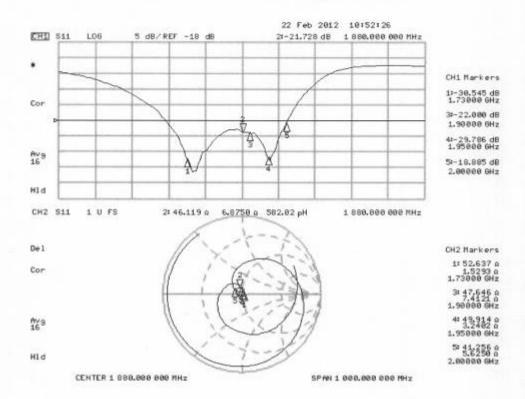
The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

#### Impedance Measurement Plot



#### **DASY5 H-field Result**

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

#### DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1115

Communication System: CW; Frequency: 1880 MHz Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY52 Configuration:

- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

#### Dipole H-Field measurement @ 1880MHz/H-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

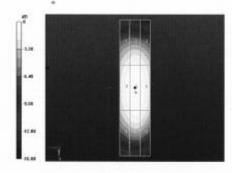
Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.50 V/m; Power Drift = -0.01 dB

PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.47 A/m Near-field category: M2 (AWF 0 dB)

PMF scaled H-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
0.40 A/m	0.43 A/m	0.41 A/m
Grid 4 M2 0.45 A/m		
Grid 7 M2	Grid 8 M2	Grid 9 M2
0.41 A/m	0.44 A/m	0.42 A/m



0 dB = 0.47 A/m = -6.56 dB A/m

#### **DASY5 E-field Result**

Date: 21.02.2012

Test Laboratory: SPEAG Lab2

#### DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1115

Communication System: CW; Frequency: 1880 MHz

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000 \text{ kg/m}^3$ 

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.04.2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.0(692); SEMCAD X 14.6.4(4989)

#### Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Device Reference Point: 0, 0, -6.3 mm Reference Value = 161.1 V/m; Power Drift = -0.01 dB

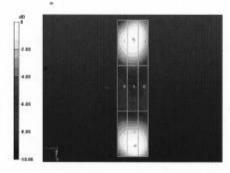
PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 143.4 V/m

Near-field category: M2 (AWF 0 dB)

PMF scaled E-field

	Grid 2 M2 139.6 V/m	Grid 3 M2 136.5 V/m
Grid 4 M3 90.34 V/m	Grid 5 M3 93.17 V/m	Grid 6 M3 89.93 V/m
	Grid 8 M2 143.4 V/m	Grid 9 M2 141.8 V/m



0 dB = 143.4V/m = 43.13 dB V/m

## **ANNEX G: DAE4 Calibration Certificate**

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Client

TA Shanghai (Auden)

Certificate No: DAE4-1317 Jan12

Accreditation No.: SCS 108

i A Silangilai (/		HITCHING I DOWN I I	Definicate No: DAE4-1317_3a1112
ALIBRATION C	ERTIFICATE		
Dbject	DAE4 - SD 000 D	04 BJ - SN: 1317	
Calibration procedure(s)	QA CAL-06.v24 Calibration proces	dure for the data acquis	sition electronics (DAE)
Calibration date:	January 23, 2012		
he measurements and the unce	rtainties with confidence pro	obability are given on the follow	e physical units of measurements (SI).  sing pages and are part of the certificate.  sure (22 ± 3)°C and humidity < 70%.
rimary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
eithley Multimeter Type 2001	SN: 0810278	28-Sep-11 (No:11450)	Sep-12
econdary Standards	ID#	Check Date (in house)	Scheduled Check
alibrator Box V2.1	SE UWS 053 AA 1001	05-Jan-12 (in house check)	In house check: Jan-13
	•		
	Name	Function	Signature
calibrated by:	Dominique Steffen	Technician	*
approved by:	Fin Bomholt	R&D Director	F. Bridall
			Issued: January 23, 2012
	27 St 22 St 22	full without written approval of the	

Certificate No: DAE4-1317\_Jan12

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kallbrierdienst

Service suisse d'étalonnage

C Servizio svizzero di taratura

Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

#### Glossary

DAE

data acquisition electronics

Connector angle

information used in DASY system to align probe sensor X to the robot

coordinate system.

## Methods Applied and Interpretation of Parameters

- DC Voltage Measurement: Calibration Factor assessed for use in DASY system by comparison with a calibrated instrument traceable to national standards. The figure given corresponds to the full scale range of the voltmeter in the respective range.
- Connector angle: The angle of the connector is assessed measuring the angle mechanically by a tool inserted. Uncertainty is not required.
- The following parameters as documented in the Appendix contain technical information as a result from the performance test and require no uncertainty.
  - DC Voltage Measurement Linearity: Verification of the Linearity at +10% and -10% of the nominal calibration voltage. Influence of offset voltage is included in this measurement.
  - Common mode sensitivity: Influence of a positive or negative common mode voltage on the differential measurement.
  - Channel separation: Influence of a voltage on the neighbor channels not subject to an input voltage.
  - AD Converter Values with inputs shorted: Values on the internal AD converter corresponding to zero input voltage
  - Input Offset Measurement: Output voltage and statistical results over a large number of zero voltage measurements.
  - Input Offset Current: Typical value for information; Maximum channel input offset current, not considering the input resistance.
  - Input resistance: Typical value for information: DAE input resistance at the connector, during internal auto-zeroing and during measurement.
  - Low Battery Alarm Voltage: Typical value for information. Below this voltage, a battery alarm signal is generated.
  - Power consumption: Typical value for information. Supply currents in various operating modes.

# TA Technology (Shanghai) Co., Ltd. Test Report

Report No. RXA1204-0050HAC01

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## **DC Voltage Measurement**

A/D - Converter Resolution nominal

High Range:

1LSB =

 $B = 6.1 \mu V$ ,

full range = -100...+300 mV

Low Range:

1LSB =

61nV

full range = -1.....+3mV

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Calibration Factors	X	Y	Z
High Range	404.064 ± 0.1% (k=2)	404.056 ± 0.1% (k=2)	403.955 ± 0.1% (k=2)
Low Range	3.98762 ± 0.7% (k=2)	3.98737 ± 0.7% (k=2)	3.98343 ± 0.7% (k=2)

### **Connector Angle**

Connector Angle to be used in DASY system	117.0 ° ± 1 °

Certificate No: DAE4-1317\_Jan12

#### **Appendix**

1. DC Voltage Linearity

High Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	199992.18	-1.75	-0.00
Channel X + Input	20001.35	0.46	0.00
Channel X - Input	-19997.31	1.96	-0.01
Channel Y + Input	199993.18	-1.24	-0.00
Channel Y + Input	20001.40	0.60	0.00
Channel Y - Input	-20000.04	-0.70	0.00
Channel Z + Input	199991.58	-2.43	-0.00
Channel Z + Input	19999.62	-1.14	-0.01
Channel Z - Input	-20001.31	-1.83	0.01

Low Range	Reading (μV)	Difference (μV)	Error (%)
Channel X + Input	2000.74	-0.89	-0.04
Channel X + Input	202.18	-0.01	-0.01
Channel X - Input	-197.58	0.36	-0.18
Channel Y + Input	2000.34	-1.20	-0.06
Channel Y + Input	199.67	-2.39	-1.18
Channel Y - Input	-197.64	0.32	-0.16
Channel Z + Input	2000.69	-0.78	-0.04
Channel Z + Input	200.84	-1.16	-0.57
Channel Z - Input	-198.45	-0.47	0.24

## 2. Common mode sensitivity

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Common mode Input Voltage (mV)	High Range Average Reading (μV)	Low Range Average Reading (μV)
Channel X	200	-23.40	-24.98
	- 200 *	28.01	26.12
Channel Y	200	-2.57	-2.75
	- 200	1.67	1.31
Channel Z	200	-11.92	-11.43
	- 200	9.80	9.45

### 3. Channel separation

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

	Input Voltage (mV)	Channel X (μV)	Channel Y (µV)	Channel Z (μV)
Channel X	200		-2.15	-4.41
Channel Y	200	7.18		-2.47
Channel Z	200	7.44	5.46	

#### 4. AD-Converter Values with inputs shorted

DASY measurement parameters: Auto Zero Time; 3 sec; Measuring time; 3 sec

	High Range (LSB)	Low Range (LSB)
Channel X	16081	17027
Channel Y	16103	16170
Channel Z	16221	16651

#### 5. Input Offset Measurement

DASY measurement parameters: Auto Zero Time: 3 sec; Measuring time: 3 sec

Input  $10M\Omega$ 

	Average (μV)	min. Offset (μV)	max. Offset (μV)	Std. Deviation (µV)
Channel X	-0.45	-1.32	0.40	0.32
Channel Y	-2.63	-3.99	-1.68	0.42
Channel Z	-0.67	-3.07	1.36	0.50

#### 6. Input Offset Current

Nominal Input circuitry offset current on all channels: <25fA

7. Input Resistance (Typical values for information)

	Zeroing (kOhm)	Measuring (MOhm)
Channel X	200	200
Channel Y	200	200
Channel Z	200	200

8. Low Battery Alarm Voltage (Typical values for information)

Typical values	Alarm Level (VDC)	
Supply (+ Vcc)	+7.9	
Supply (- Vcc)	-7.6	

9. Power Consumption (Typical value's for information)

Typical values	Switched off (mA)	Stand by (mA)	Transmitting (mA)
Supply (+ Vcc)	+0.01	+6	+14
Supply (- Vcc)	-0.01	-8	-9

## **ANNEX H: The EUT Appearances and Test Configuration**



a: EUT





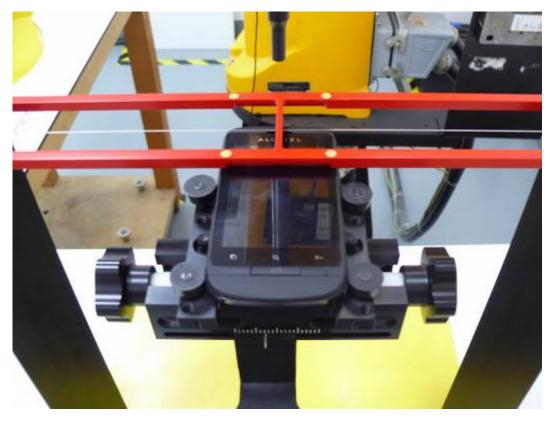
b: Battery 1





c: Battery 2

**Picture 1: Constituents of EUT** 



Picture 2: Test Setup